

Schottky Barrier Diode

1SS389

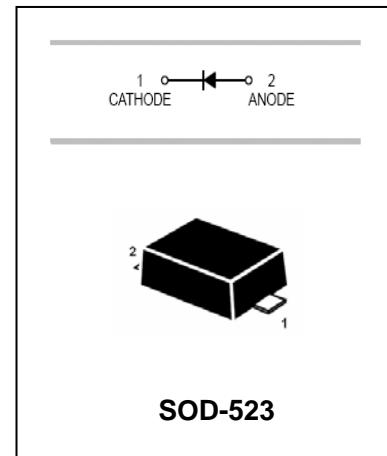
FEATURES

- Low forward voltage.
- Small package.



APPLICATIONS

- Schottky diode in surface mounted circuits.



ORDERING INFORMATION

Type No.	Marking	Package Code
1SS389	S4	SOD-523

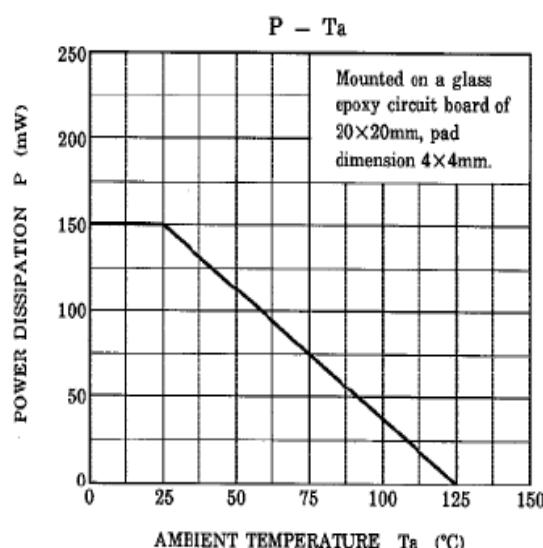
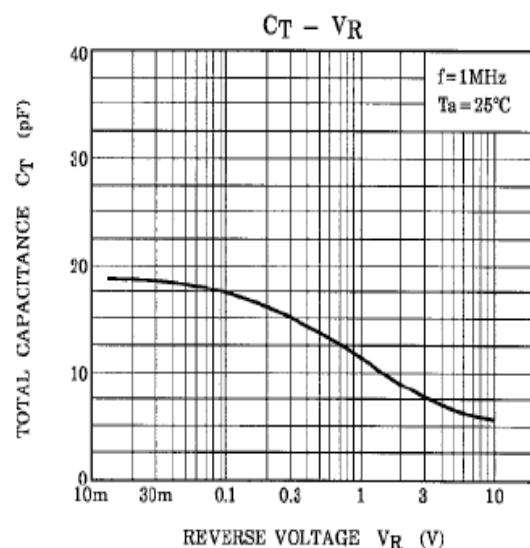
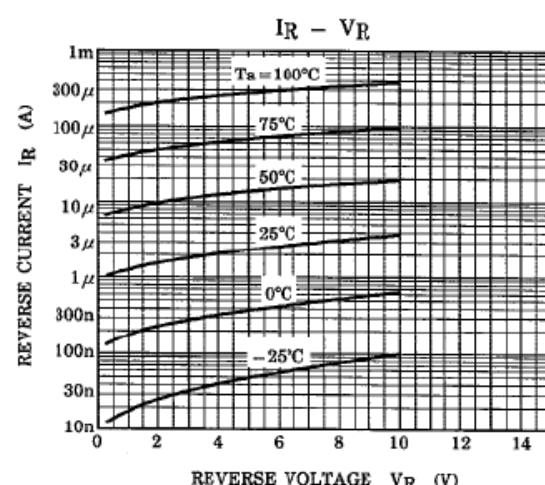
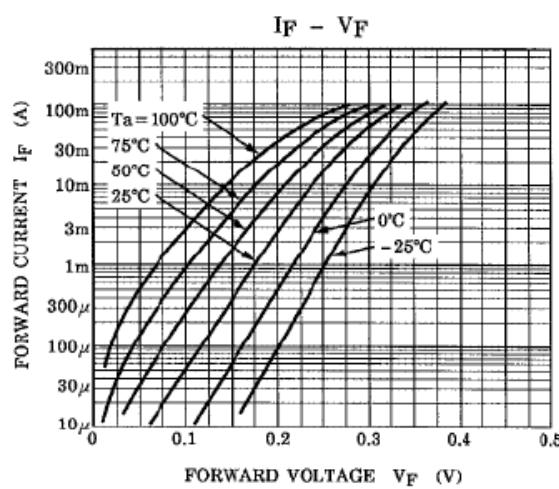
MAXIMUM RATING @ Ta=25°C unless otherwise specified

Parameter	Symbol	Limits	Unit
Peak reverse voltage	V _{RM}	15	V
DC Reverse voltage	V _R	10	V
Continuous forward current	I _F	100	mA
Surge current	I _{FSM}	1	A
Total power dissipation	P _{tot}	150	mW
Junction temperature	T _j	125	°C
Storage temperature	T _{stg}	-55-125	°C

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse breakdown voltage	V _{(BR)R}	10			V	I _R =100µA
Forward voltage	V _F		0.18		V	I _F =1mA
			0.23	0.30	V	I _F =5mA
			0.35	0.50	V	I _F =100mA
Reverse current	I _R			20	µA	V _R =10V
Diode capacitance	C _d		20	40	pF	V _R =0,f=1MHz

TYPICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified



Diode Semiconductor Korea

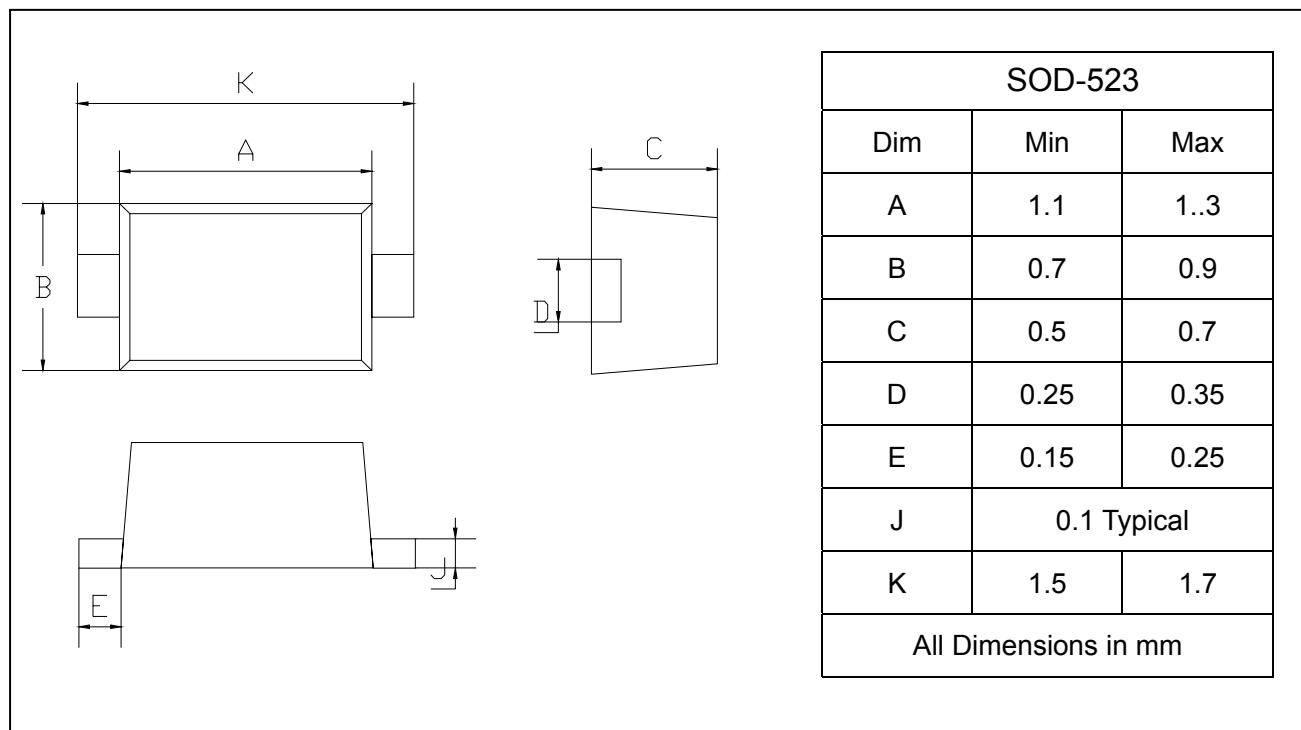
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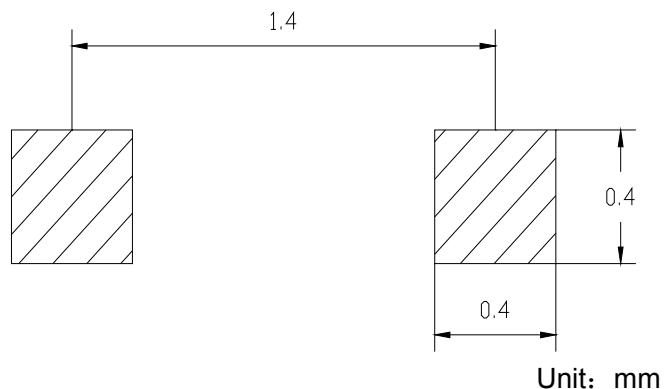
PACKAGE OUTLINE

Plastic surface mounted package

SOD-523



SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
1SS389	SOD-523	3000/Tape&Reel